NSN 5961-00-181-0662

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View Online at https://aerobasegroup.com/nsn/5961-00-181-0662 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.328 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: static, collector open

700.0 collector to base voltage/static/emitter open and 500.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage,

Current Rating Per Characteristic:

Between 2.00 amperes source cutoff current and 3.50 amperes source cutoff current

Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector preset

Special Features:

Junction pattern arrangement: npn

Test Data Document:

81349-mil-prf-15900 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Specification Data:

81349-mil-prf-19500/371 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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Mil-std (military Standard):

Mil-prf-15900 spec.